NSN 5961-01-239-6524

Transistor - Page 1 of 1



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Mounting Facility Quantity: 2 Internal Configuration: Junction contact Mounting Method: Unthreaded hole Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 50.0 collector-to-emitter, substaining voltage, base open-circuited and 4.0 emitt to base voltage, static, collector open Current Rating Per Characteristic: 16.00 amperes all primaries Special Features: Junction pattern arrangement: npn Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Filig:	
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